## NSN 5961-00-489-0359

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.405 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.250 inches
Thread Size:
0.138 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, peak
Current Rating Per Characteristic:
9.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Precious Material And Location:
External surfaces gold
Precious Material:
Gold
Thread Series Designator:
Unc
Terminal Type And Quantity:
1 threaded stud and 1 turret
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Filig:
A110a0